

UPG11N120ND

Insulated Gate Bipolar Transistor

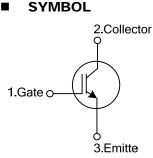
1200V NPT PLANAR IGBT

DESCRIPTION

The UTC **UPG11N120ND** is a 1200V NPT Planar Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to offers superior conduction and switching performance, high avalanche ruggedness and easy parallel operation.

FEATURES

- * High speed switching
- * High input impedance
- * Low saturation voltage: $V_{CE(SAT)}$ = 2.4V @ I_C=11A, V_{GE}=15V



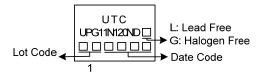
ORDERING INFORMATION

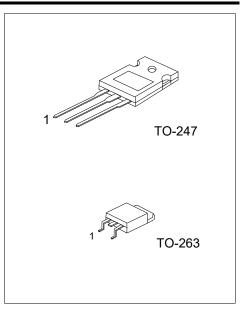
Ordering Number		Deskere	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UPG11N120NDL-T47-T	UPG11N120NDG-T47-T	TO-247	G	С	E	Tube	
UPG11N120NDL-TQ2-T	UPG11N120NDG-TQ2-T	TO-263	G	С	E	Tube	
UPG11N120NDL-TQ2-R	UPG11N120NDG-TQ2-R	TO-263	G	С	E	Tape Reel	
Note: Pin Assignment: G: Gate C: Collector E: Emitter							

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UPG11N120ND <u>G-T47-T</u>	
(1)Packing Type	(1) T: Tube, R: Tape Reel
(2)Package Type	(2) T47: TO-247, TQ2: TO-263
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free
1	

MARKING





ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V _{CES}	1200	V	
Gate-Emitter Voltage		V _{GES}	±20	V	
Continuous Collector Current	T _C =25°C	lc	35	А	
	T _c =110°C		17	А	
Collector Current Pulsed (Note 1)		Ісм	80	А	
Power Dissipation	TO-247		300	W	
	TO-263	PD	90	W	
Operating Junction Temperature		TJ	-55 ~ +150	°C	
Storage Temperature Range		T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

2. Pulse width limited by maximum junction temperature.

THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT	
lumetion to Coop	TO-247	0	0.42	°C/W	
Junction to Case	TO-263	θις	1.39	°C/W	

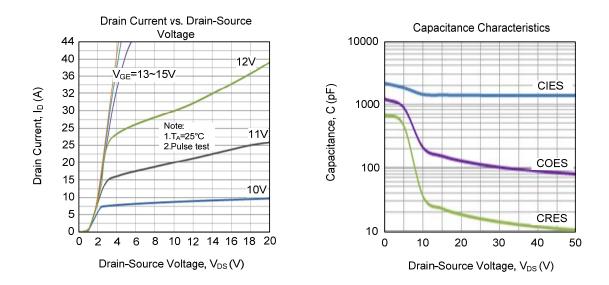
■ ELECTRICAL CHARACTERISTICS (Tc=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	ΜΔΧ			
PARAMETER SYMBOL TEST CONDITIONS MIN TYP MAX UNIT OFF CHARACTERISTICS								
Collector-Emitter Breakdown Voltage	BVCES	Ic=250µA, V _{GE} =0V	1200			V		
Collector Cut-Off Current	ICES	V _{CE} =V _{CES} , V _{GE} =0V			250	μA		
G-E Leakage Current	IGES	V _{GE} =V _{GES} , V _{CE} = 0V			±250	nA		
ON CHARACTERISTICS								
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		7.5	V		
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =11A, V _{GE} =15V		2.1	2.4	V		
DYNAMIC CHARACTERISTICS								
Input Capacitance	CIES			1510		pF		
Output Capacitance	COES	V _{CE} =25V, V _{GE} =0V, f=1MHz		118		рF		
Reverse Transfer Capacitance	CRES			14		рF		
SWITCHING CHARACTERISTICS			<u>.</u>					
Total Gate Charge	Q _G			78		nC		
Gate-Emitter Charge	Q _{GE}	V _{CE} =600V, V _{GE} =15V, I _C =11A		23		nC		
Gate-Collector Charge	Q _{GC}			30		nC		
Turn-On Delay Time	t _{D(ON)}			10		ns		
Rise Time	t _R			17		ns		
Turn-Off Delay Time	t _{D(OFF)}	V _{CC} =600V, V _{GE} =15V, I _C =11A,		52		ns		
Fall Time	tF	R _G =10Ω, L=500uH		266		ns		
Turn-On Switching Loss	Eon			0.36		mJ		
Turn-Off Switching Loss	EOFF			0.74		mJ		



UPG11N120ND

TYPICAL CHARACTERISTICS



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